CEZ06R10SLC

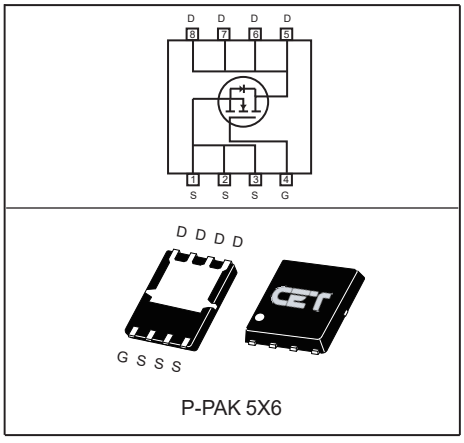
N-Channel Enhancement Mode Field Effect Transistor

PRELIMINARY

V_{DSS}	$R_{DS(ON)\ typ}$	I_D	@V_{GS}
100V	6.1mΩ	66A	10V
	7.9mΩ		4.5V

FEATURES

- High power and current handing capability.
- Pb-free lead plating ; RoHS compliant.
- Halogen Free.
- Surface mount Package.



P-PAK 5X6

APPLICATIONS

- DC to DC Converter.
- Power over Ethernet.
- Adapter.
- Battery Management System.

ABSOLUTE MAXIMUM RATINGS

T_C = 25°C unless otherwise noted

Parameter		Symbol	Limit	Units
Drain-Source Voltage		V_{DS}	100	V
Gate-Source Voltage		V_{GS}	±20	V
Drain Current-Continuous	I_D @$R_{\theta JC}$	T_C =25°C	66	A
		T_C =100°C	42	A
	I_D @$R_{\theta JA}$	T_A =25°C	21	A
		T_A =100°C	14	A
Drain Current-Pulsed [a]	I_{DM} @$R_{\theta JC}$	T_C =25°C	264	A
	I_{DM} @$R_{\theta JA}$	T_A =25°C	84	A
Maximum Power Dissipation		P_D	59.5	W
Operating and Store Temperature Range		T_J,T_{stg}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Limit	Units
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.1	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	20	°C/W

This is preliminary information on a new product in development now
Details are subject to change without notice .

2024.Dec
http://www.cet-mos.com

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} = 0V, I_D = 250μA	100			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 100V, V_{GS} = 0V			1	μA
Gate Body Leakage Current, Forward	I_{GSSF}	V_{GS} = 20V, V_{DS} = 0V			100	nA
Gate Body Leakage Current, Reverse	I_{GSSR}	V_{GS} = -20V, V_{DS} = 0V			-100	nA
On Characteristics [b]						
Gate Threshold Voltage	$V_{GS(th)}$	V_{GS} = V_{DS}, I_D = 250μA	1		3	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS} = 10V, I_D = 20A		6.1	7.5	mΩ
		V_{GS} = 4.5V, I_D = 20A		7.9	10.2	mΩ
Gate input resistance	R_g	f=1MHz,open Drain		1.9		Ω
Dynamic Characteristics [c]						
Input Capacitance	C_{iss}	V_{DS} = 50V, V_{GS} = 0V, f = 1.0 MHz		1725		pF
Output Capacitance	C_{oss}			630		pF
Reverse Transfer Capacitance	C_{rss}			15		pF
Switching Characteristics [c]						
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = 80V, I_D = 20A, V_{GS} = 10V, R_{GEN} = 6Ω		21		ns
Turn-On Rise Time	t_r			10		ns
Turn-Off Delay Time	$t_{d(off)}$			46		ns
Turn-Off Fall Time	t_f			11		ns
Total Gate Charge	Q_g	V_{DS} = 80V, I_D = 10A, V_{GS} = 4.5V		14		nC
Gate-Source Charge	Q_{gs}			3		nC
Gate-Drain Charge	Q_{gd}			8		nC
Drain-Source Diode Characteristics and Maximun Ratings						
Drain-Source Diode Forward Current	I_S				49	A
Drain-Source Diode Forward Voltage [b]	V_{SD}	V_{GS} = 0V, I_S = 1A			1.2	V

Notes :
a.Repetitive Rating : Pulse width limited by maximum junction temperature.
b.Pulse Test : Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
c.Guaranteed by design, not subject to production testing.

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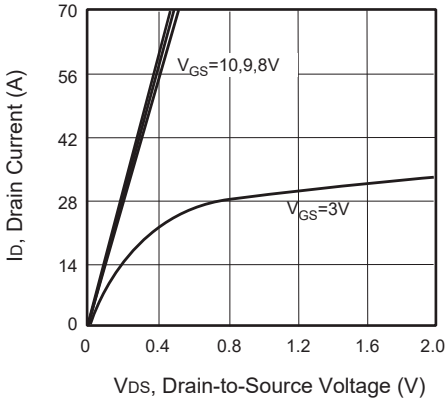


Figure 1. Output Characteristics

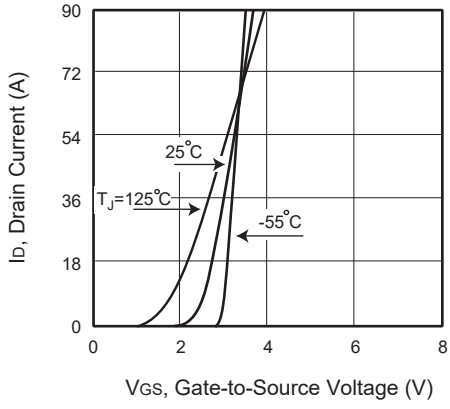


Figure 2. Transfer Characteristics

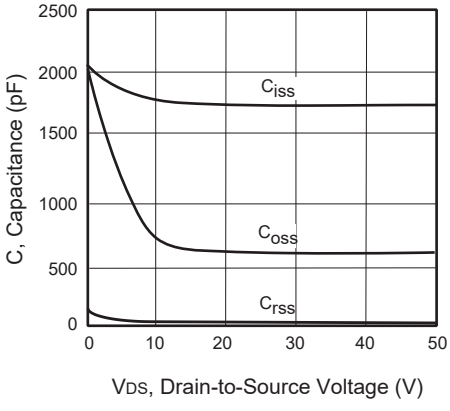


Figure 3. Capacitance

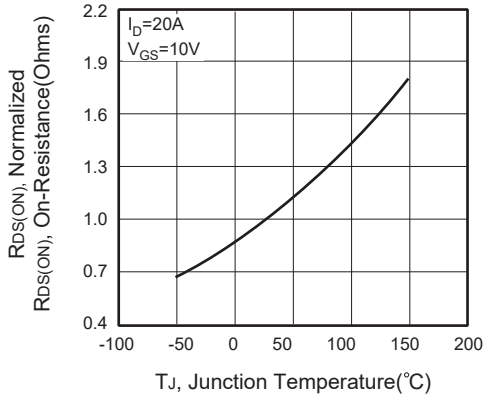


Figure 4. On-Resistance Variation with Temperature

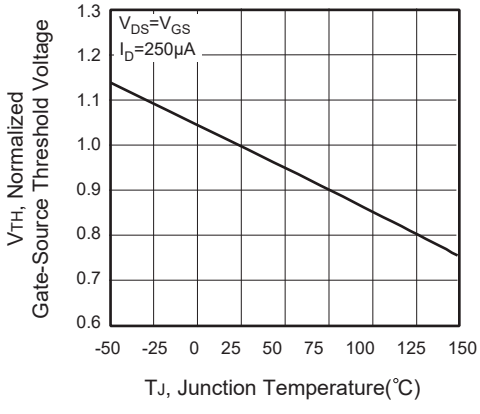


Figure 5. Gate Threshold Variation with Temperature

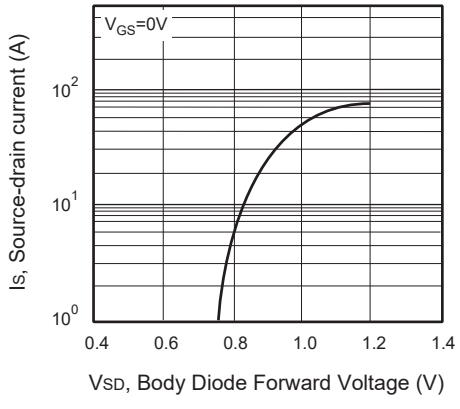


Figure 6. Body Diode Forward Voltage Variation with Source Current

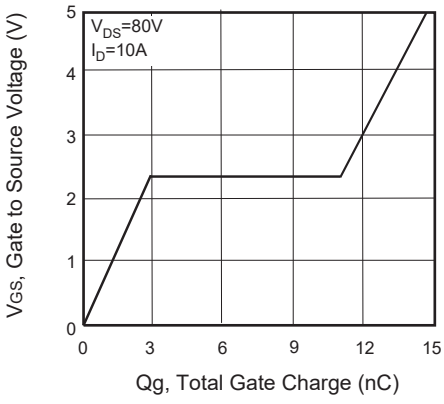


Figure 7. Gate Charge

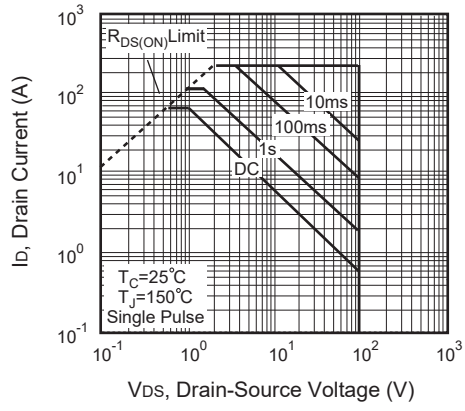


Figure 8. Maximum Safe Operating Area

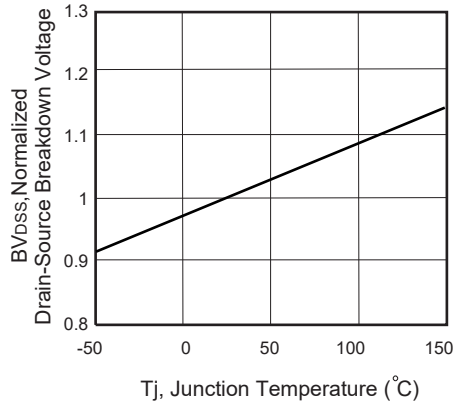


Figure 9. Breakdown Voltage Variation VS Temperature

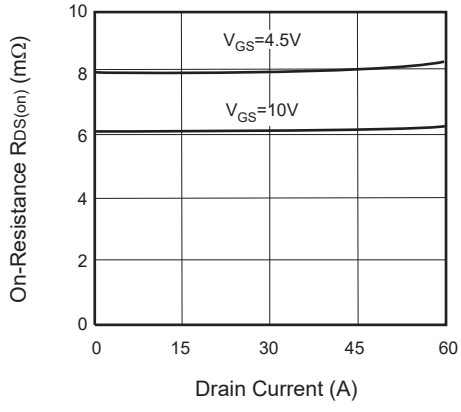


Figure 10. On-Resistance vs. Drain Current

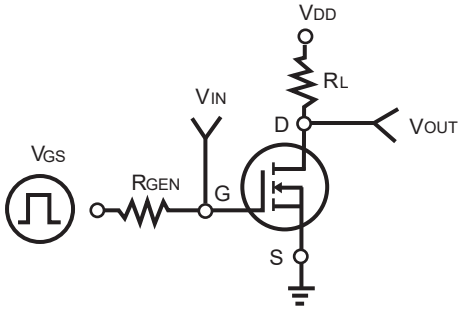


Figure 11. Switching Test Circuit

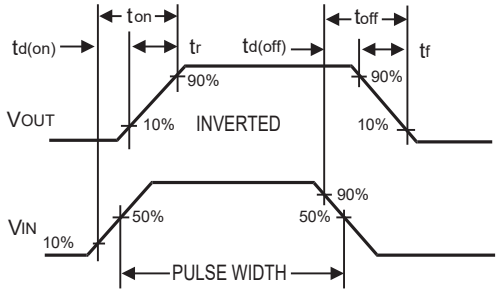


Figure 12. Switching Waveforms

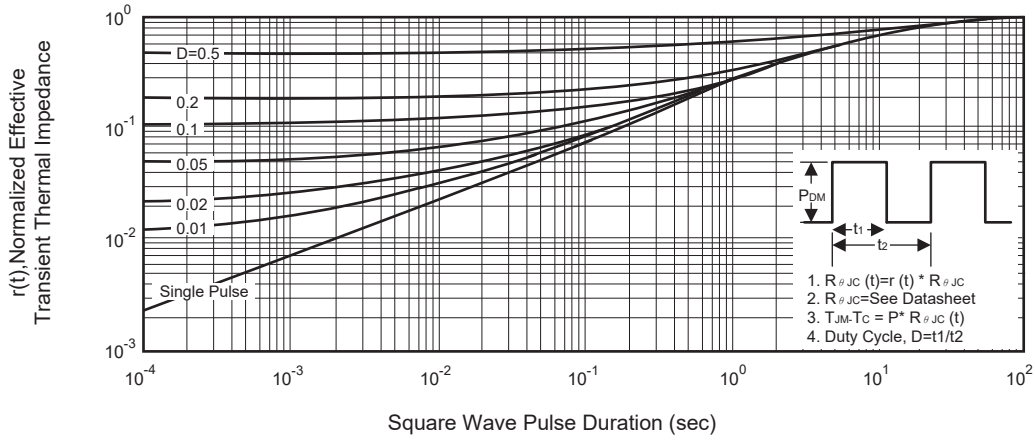
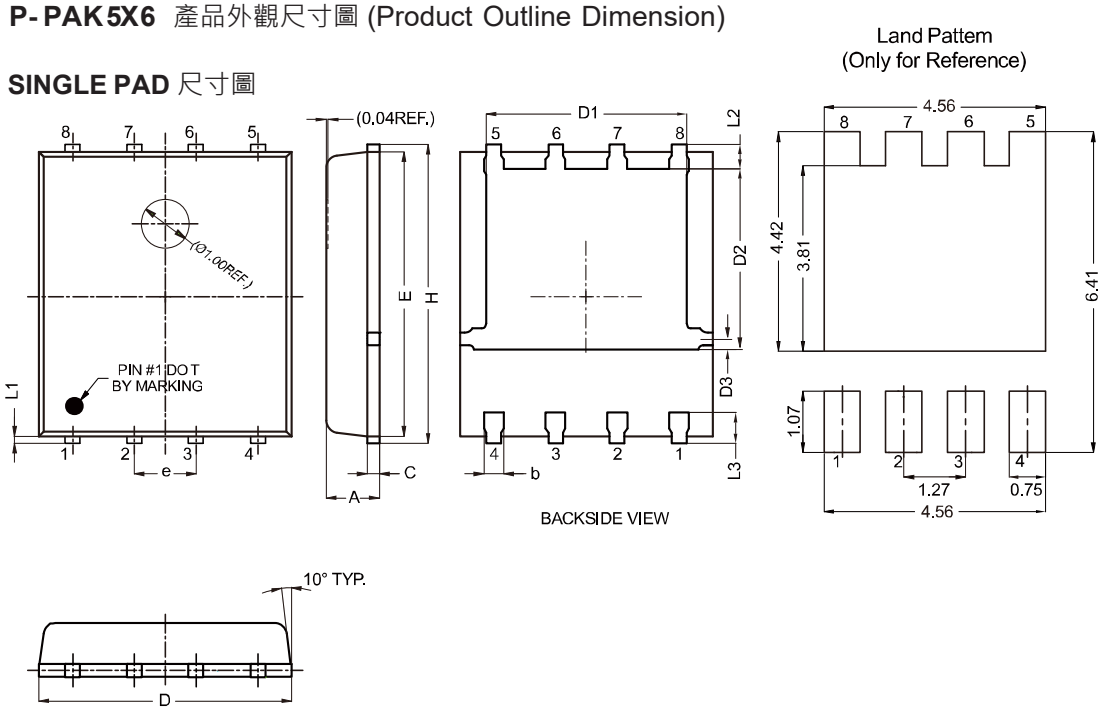


Figure 13. Normalized Thermal Transient Impedance Curve

P-PAK5X6 產品外觀尺寸圖 (Product Outline Dimension)

SINGLE PAD 尺寸圖



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.000	1.200	0.039	0.047
b	0.300	0.500	0.012	0.020
c	0.154	0.354	0.006	0.014
D	5.050	5.350	0.199	0.211
D1	3.800	4.250	0.150	0.167
D2	3.570	3.970	0.141	0.156
D3	0.380	0.850	0.015	0.033
E	5.660	6.060	0.223	0.239
e	1.270 TYP		0.050 TYP	
H	6.000	6.300	0.236	0.248
L1	0.080	0.330	0.003	0.013
L2	0.400	0.600	0.016	0.024
L3	0.500	0.700	0.020	0.028